NSN 5961-01-564-9795

Transistor - Page 1 of 1



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Inclosure Material:

Metal

Overall Length:

19.6 millimeters

Terminal Length:

13.2 millimeters

Overall Diameter:

4.7 millimeters

Function For Which Designed:

Phototransistor

Mounting Method:

Terminal

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

70.0 breakdown voltage, collector-to-emitter, base open

Current Rating Per Characteristic:

100.00 nanoamperes zero-gate-voltage source current absolute

Power Rating Per Characteristic:

250.0 milliwatts small-signal input power, common-collector preset

Special Features:

Lens window; high photo sensitivity; lead (pb)-free component

Terminal Type And Quantity:

3 pin

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

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